Quantity

per reel

2500

ZXMN6A09KTC

Device marking

ZXMN 6A09K

Device

Ordering information

Reel size

(inches)

13

•	Disconnect switches
•	Motor control

• DC-DC converters

٠

Applications

- Features
- Low on-resistance
- · Fast switching speed
- Low threshold
- · Low gate drive
- DPAK (T0-252) package

Power management functions

60V N-channel enhancement mode MOSFET in DPAK

Summary

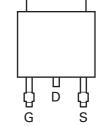
ZXMN6A09K

V_{(BR)DSS}=60V : R_{DS(on)}=0.040Ω; I_D=12.2A

Description

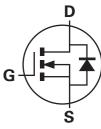
This new generation of trench MOSFETs from Zetex utilizes a unique structure that combines the benefits of low on-resistance with fast switching speed. This makes them ideal for high efficiency, low voltage power management applications.

D



D

Pinout - top view





Tape width

(mm)

16

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Drain-source voltage	V _{DSS}	60	V
Gate-source voltage	V _{GS}	±20	V
Continuous drain current @V _{GS} =10V; T _{amb} =25°C ^(b)	۱ _D	12.2	А
@ V _{GS} =10V; T _{amb} =70°C ^(b)		9.8	
@ V _{GS} =10V; T _{amb} =25°C ^(a)		7.9	
Pulsed drain current ^(c)	I _{DM}	43	А
Continuous source current (body diode) ^(b)	۱ _S	10.8	А
Pulsed source current (body diode) ^(c)	I _{SM}	43	А
Power dissipation at $T_{amb} = 25^{\circ}C^{(a)}$	P _D	4.3	W
Linear derating factor		34.4	mW/°C
Power dissipation at $T_{amb} = 25^{\circ}C^{(a)}$	P _D	10.1	W
Linear derating factor		80.8	mW/°C
Power dissipation at $T_{amb} = 25^{\circ}C^{(a)}$	PD	2.15	W
Linear derating factor		17.2	mW/°C
Operating and storage temperature range	T _j , T _{stg}	-55 to +150	°C

Thermal resistance

Parameter	Symbol	Limit	Unit
Junction to ambient ^(a)	$R_{\Theta JA}$	29	°C/W
Junction to ambient ^(b)	R_{\ThetaJA}	12.3	°C/W
Junction to ambient ^(d)	R_{\ThetaJA}	58.1	°C/W

NOTES:

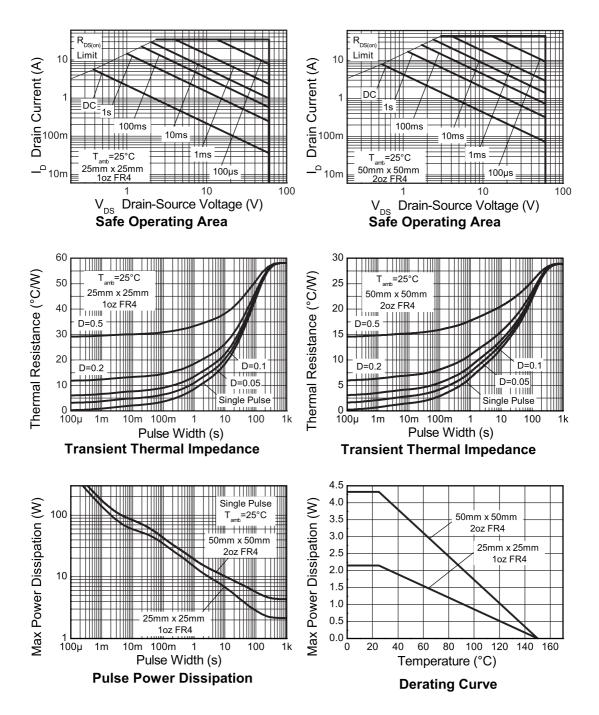
(a) For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.

(b) For a device surface mounted on FR4 PCB measured at t ${\leq}10$ sec.

(c) Repetitive rating 50mm x 50mm x 1.6mm FR4 PCB, D=0.02 pulse width=300 μ s - pulse width limited by maximum junction temperature.

(d) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

Characteristics



Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Static	1					1
Drain-source breakdown voltage	V _{(BR)DSS}	60			V	I_{D} = 250 μ A, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}			1	μA	V _{DS} = 60V, V _{GS} =0V
Gate-body leakage	I _{GSS}			100	nA	$V_{GS}=\pm 20V, V_{DS}=0V$
Gate-source threshold voltage	V _{GS(th)}	1.0		3.0	V	$I_D = 250 \mu A, V_{DS} = V_{GS}$
Static drain-source on-state	R _{DS(on)}			0.040	Ω	V _{GS} = 10V, I _D = 7.3A
resistance ^(*)				0.060	Ω	V_{GS} = 4.5V, I_{D} = 5.6A
Forward transconductance ^{(*)(‡)}	g _{fs}		15		S	V _{DS} = 15V, I _D = 7.3A
Dynamic ^(‡)						·
Input capacitance	C _{iss}		1426		pF	V _{DS} = 30V, V _{GS} =0V
Output capacitance	C _{oss}		134		pF	f=1MHz
Reverse transfer capacitance	C _{rss}		64		pF	
Switching ^(†) ^(‡)	•	+	4	4	<u>.</u>	
Turn-on-delay time	t _{d(on)}		4.8		ns	V _{DD} = 30V, I _D = 1A
Rise time	t _r		4.6		ns	$R_{G} \cong 6.0\Omega$, $V_{GS} = 10V$
Turn-off delay time	t _{d(off)}		32.5		ns	(refer to test circuit)
Fall time	t _f		14.5		ns	
Total gate charge	Qg		15		nC	V _{DS} = 30V, V _{GS} = 4.5V I _D = 5.6A
Total gate charge	Qg		29		nC	V _{DS} = 30V, V _{GS} = 10V
Gate-source charge	Q _{gs}		7.0		nC	I _D = 7.3A
Gate drain charge	0 _{gd}		4.7		nC	
Source-drain diode	•					
Diode forward voltage ^(*)	V _{SD}		0.85	0.95	V	$T_j=25^{\circ}C$, $I_S=6.6A$, $V_{GS}=0V$
Reverse recovery time ^(‡)	t _{rr}		25.6		ns	T _j =25°C, I _S = 3A,
Reverse Recovery charge ^(‡)	Q _{rr}		26.0		nC	di/dt=100A/μs

Electrical characteristics (at $T_{amb} = 25^{\circ}C$ unless otherwise stated)

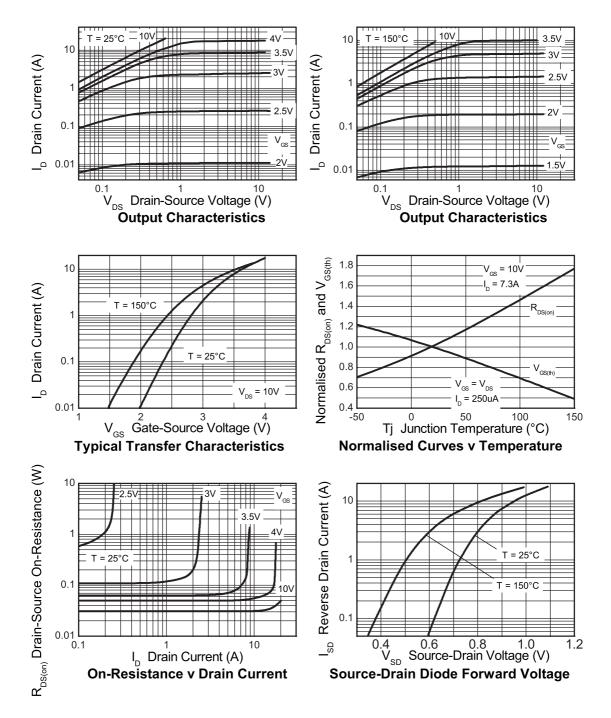
NOTES:

(*) Measured under pulsed conditions. Pulse width \leq 300 s; duty cycle \leq 2%.

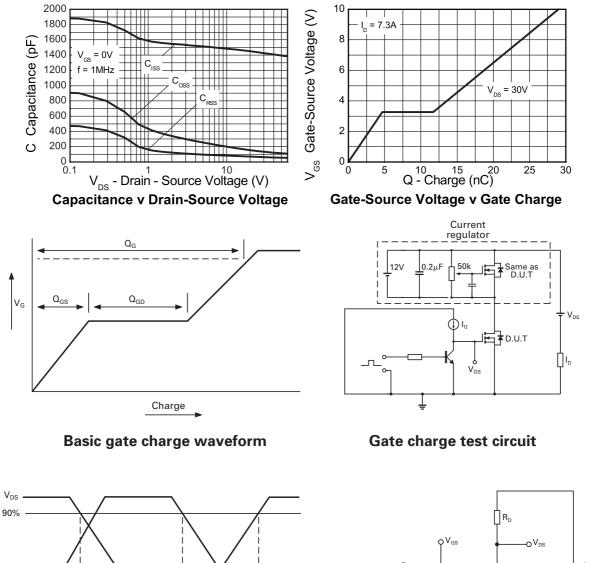
(†) Switching characteristics are independent of operating junction temperature.

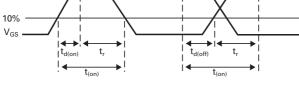
(‡) For design aid only, not subject to production testing.

Typical characteristics

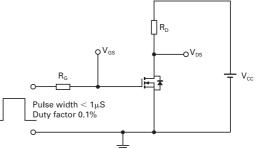


Typical characteristics



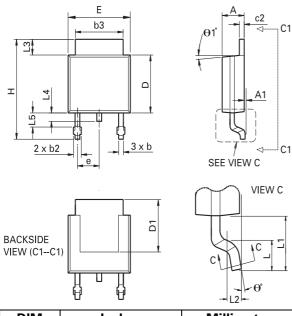


Switching time waveforms



Switching time test circuit

Package outline - DPAK



DIM	Inches		Millin	Millimeters		Inches		Millin	neters
	Min	Max	Min	Max		Min	Max	Min	Max
А	0.086	0.094	2.18	2.39	е	0.090) BSC	2.29	BSC
A1	-	0.005	-	0.127	Н	0.370	0.410	9.40	10.41
b	0.020	0.035	0.508	0.89	L	0.055	0.070	1.40	1.78
b2	0.030	0.045	0.762	1.14	L1	0.108	3 REF	2.74	REF
b3	0.205	0.215	5.21	5.46	L2	0.020) BSC	0.508	BSC
С	0.018	0.024	0.457	0.61	L3	0.035	0.065	0.89	1.65
c2	0.018	0.023	0.457	0.584	L4	0.025	0.040	0.635	1.016
D	0.213	0.245	5.41	6.22	L5	0.045	0.060	1.14	1.52
D1	0.205	-	5.21	-	θ1°	0°	10°	0°	10°
E	0.250	0.265	6.35	6.73	θ°	0°	15°	0°	15°
E1	0.170	-	4.32	-	-	-	-	-	-

Note: Controlling dimensions are in inches. Approximate dimensions are provided in millimeters

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